

Vishay Semiconductors

## ADD-A-PAK Gen 7 Power Modules Standard Diodes, 100 A



PRODUCT SUMMARY						
I <sub>F(AV)</sub>	100 A					
Type	Modules - Diode, High Voltage					
Package ADD-A-PAK Gen 7						
Circuit	Two diodes doubler circuit, two diodes common cathode, two diodes common anode,					

#### **MECHANICAL DESCRIPTION**

The ADD-A-PAK Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

#### **FEATURES**

- · High voltage
- · Industrial standard package
- UL approved file E78996



- · Low thermal resistance
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

#### **BENEFITS**

- · Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- · Easy mounting on heatsink

#### **ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	112 °C	100					
I <sub>F(RMS)</sub>		157	1				
1	50 Hz	2020	А				
IFSM	60 Hz	z 2115					
l <sup>2</sup> t	50 Hz	20.41	kA <sup>2</sup> s				
1-1	60 Hz	18.63	KA-S				
I <sup>2</sup> √t		204.1	kA²√s				
V <sub>RRM</sub>	Range	400 to 1600	V				
T <sub>J</sub>		-40 to +150	°C				
T <sub>Stg</sub>		-40 (0 +150	C				

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#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = 150 °C mA					
	04	400	500						
	06	600	700						
	08	800	900						
VS-VSK.91	10	1000	1100	10					
	12	1200	1300						
	14	1400	1500						
	16	1600	1700						

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	180° condu	ction, half sine	wave	100	A
at case temperature	, ,				112	°C
Maximum RMS forward current	I <sub>F(RMS)</sub>	DC at 90 °C	case temperat	ure	157	
		t = 10 ms	No voltage		2020	
Maximum peak, one-cycle forward,		t = 8.3  ms	reapplied		2115	Α
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		1700	
		t = 8.3  ms	reapplied	Sinusoidal half wave,	1780	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	20.41	kA <sup>2</sup> s
		t = 8.3 ms	reapplied		18.63	
		t = 10 ms	100 % V <sub>RRM</sub>		14.44	
		t = 8.3  ms	reapplied		13.18	
Maximum $I^2\sqrt{t}$ for fusing	I <sup>2</sup> √t	t = 0.1 ms t	o 10 ms, no vol	tage reapplied	204.1	kA²√s
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	$I_{F(AV)}$ , $T_J = T_J$ maximum	0.76	V
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			0.89	V
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x $\pi$ x I <sub>F(AV)</sub> < I < $\pi$ x I <sub>F(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum			2.4	mΩ
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			2.05	11122
Maximum forward voltage drop	$V_{FM}$	$I_{FM} = \pi \times I_{F(x)}$	<sub>AV)</sub> , T <sub>J</sub> = 25 °C,	t <sub>p</sub> = 400 μs square wave	1.55	V

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak reverse leakage current	I <sub>RRM</sub>	T <sub>J</sub> = 150 °C	10	mA			
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz	3000 (1 min) 3600 (1 s)	V			



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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C		
Maximum internal thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.22	°C/W		
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>	Mounting surface flat, smooth and greased	0.1			
Mounting torque ± 10 % busbar			A mounting compound is recommended and the	4	Nissa		
			torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	3	Nm		
Approximate weight				75	g		
Approximate weight	Approximate weight			2.7	OZ.		
Case style			JEDEC®	ADD-A-PAK Ge	n 7 (TO-240AA)		

ΔR CONDUCTION PER JUNCTION											
DEVICES		SINE HALF	WAVE CO	NDUCTIO	N	RECTANGULAR WAVE CONDUCTION				UNITS	
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.91	0.057	0.068	0.087	0.12	0.177	0.045	0.073	0.093	0.123	0.178	°C/W

#### Note

• Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC



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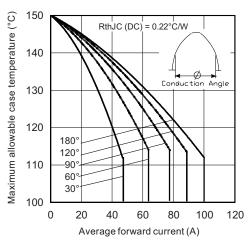


Fig. 1 - Current Ratings Characteristics

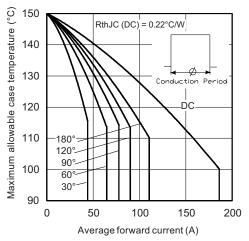


Fig. 2 - Current Ratings Characteristics

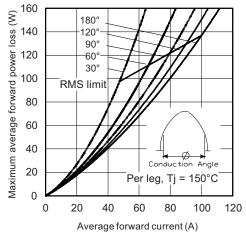


Fig. 3 - Forward Power Loss Characteristics

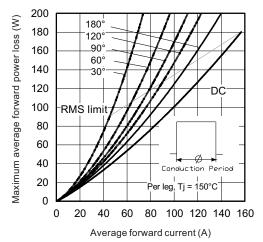
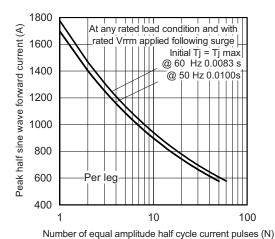


Fig. 4 - On-State Power Loss Characteristics





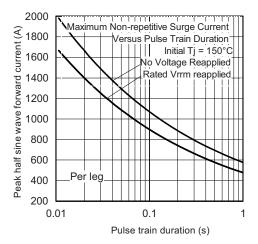


Fig. 6 - Maximum Non-Repetitive Surge Current

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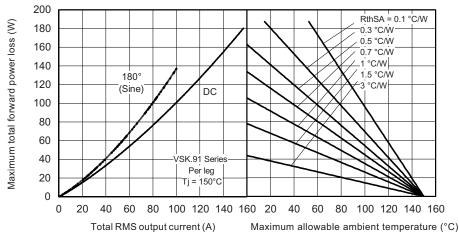


Fig. 7 - Forward Power Loss Characteristics

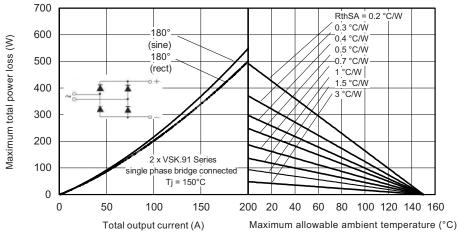


Fig. 8 - Forward Power Loss Characteristics

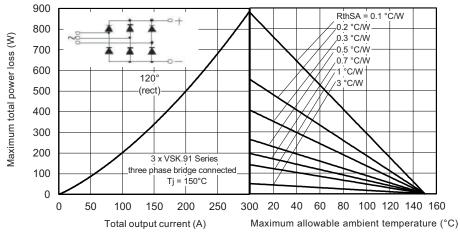


Fig. 9 - Forward Power Loss Characteristics

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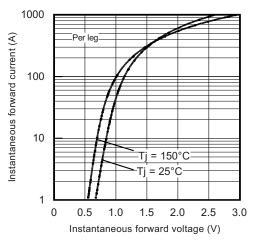


Fig. 10 - Forward Voltage Characteristics

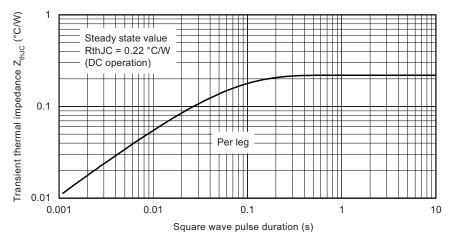


Fig. 11 - Thermal Impedance  $Z_{\text{thJC}}$  Characteristics

#### **ORDERING INFORMATION TABLE**

Device code

VS-VS K D 91 / 16

1 - Vishay Semiconductors product
2 - Module type
3 - Circuit configuration (see Circuit Configuration table)
4 - Current code (100 A)

Voltage code (see Voltage Ratings table)

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CIRCUIT CONFIGURATION		
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
		VSKD
		(1) $\tilde{\circ}$ $\dot{\circ}$ (2) $\dot{\circ}$ (3)
Two diodes doubler circuit	D	
		VSKC
		(1) 0 (2) (3)
Two diodes common cathode	С	
		VSKJ
		(1) 0 + (2) + (3)
Two diodes common anode	J	
		VSKE
	_	(1) 0 (3)
Single diode	E	

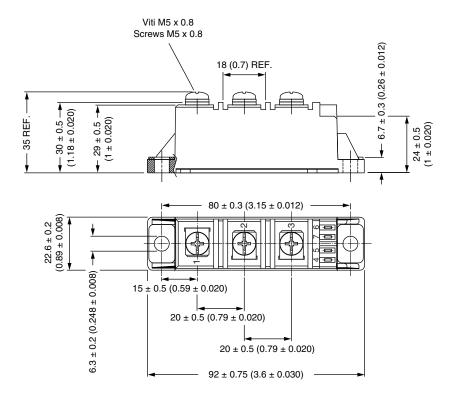
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95369		



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## **ADD-A-PAK Generation VII - Diode**

#### **DIMENSIONS** in millimeters (inches)



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